

## J108 N-CHANNEL JFET



# Linear Systems replaces discontinued Siliconix J108

This n-channel JFET is optimised for low noise high performance switching. The part is particularly suitable for use in low noise audio amplifiers. The TO-92 package is well suited for cost sensitive applications and mass production.

(See Packaging Information).

#### J108 Benefits:

- Low On Resistance
- Low insertion loss
- Low Noise

#### J108 Applications:

- Analog Switches
- Commutators
- Choppers

FEATURES					
DIRECT REPLACEMENT FOR SILICONIX J108					
LOW ON RESISTANCE	r <sub>DS(on)</sub> ≤8Ω				
FAST SWITCHING	t <sub>(on)</sub> ≤ 4ns				
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)					
Maximum Temperatures					
Storage Temperature	-55°C to +150°C				
Operating Junction Temperature	-55°C to +150°C				
Maximum Power Dissipation					
Continuous Power Dissipation	350mW				
MAXIMUM CURRENT	8				
Gate Current (Note 1)	50mA				
MAXIMUM VOLTAGES					
Gate to Drain Voltage	V <sub>GDS</sub> = -25V				
Gate to Source Voltage	V <sub>GSS</sub> = -25V				

J108 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-25				$I_G = 1\mu A$ , $V_{DS} = 0V$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	-3		-10		$V_{DS} = 5V, I_{D} = 1\mu A$
$V_{GS(F)}$	Gate to Source Forward Voltage		0.7		V	$I_G = 1 \text{mA}, V_{DS} = 0 \text{V}$
I <sub>DSS</sub>	Drain to Source Saturation Current (Note 2)	80			mA	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V
I <sub>GSS</sub>	Gate Reverse Current		-0.01	-3		$V_{GS} = -15V, V_{DS} = 0V$
I <sub>G</sub>	Gate Operating Current		-0.01		nA	$V_{DG} = 10V, I_{D} = 10mA$
I <sub>D(off)</sub>	Drain Cutoff Current		0.02	3		V <sub>DS</sub> = 5V, V <sub>GS</sub> = -10V
r <sub>DS(on)</sub>	Drain to Source On Resistance		4	8	Ω	$V_{GS} = 0V, \ V_{DS} \le 0.1V$

J108 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
g <sub>fs</sub>	Forward Transconductance		17		mS	$V_{DS} = 5V, I_D = 10 \text{mA}, f = 1 \text{kHz}$
gos	Output Conductance		0.6			
r <sub>DS(on)</sub>	Drain to Source On Resistance			8	Ω	$V_{GS} = 0V$ , $I_0 = 0A$ , $f = 1kHz$
C <sub>iss</sub>	Input Capacitance		60	85		$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
C <sub>rss</sub>	Reverse Transfer Capacitance		11	15	pF	$V_{DS} = 0V$ , $V_{GS} = -10V$ , $f = 1MHz$
$e_n$	Equivalent Noise Voltage		3.5		nV/√Hz	$V_{DS} = 5V$ , $I_{D} = 10mA$ , $f = 1kHz$

J108 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

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SYMBOL	CHARACTERISTIC		UNITS	CONDITIONS			
t <sub>d(on)</sub>	Turn On Time	3		V <sub>DD</sub> = 1.5V			
t <sub>r</sub>	Turn On Rise Time	1	ns	nc	$V_{GS}(H) = 0V$		
t <sub>d(off)</sub>	Turn Off Time	4		See Switching Circuit			
t <sub>f</sub>	Turn Off Fall Time	18					

Note 1 - Absolute maximum ratings are limiting values above which J108 serviceability may be impaired. Note 2 - Pulse test: PW  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  3% and Definition 1.00 serviceability may be impaired.

### **J108 SWITCHING CIRCUIT PARAMETERS**

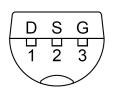
$V_{GS(L)}$	-12V
$R_L$	150Ω
I <sub>D(on)</sub>	10mA

Available Packages:

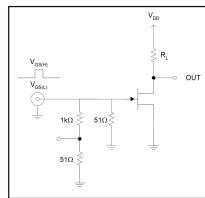
J108 in TO-92 J108 in bare die.

Please contact Micross for full package and die dimensions

TO-92 (Bottom View)



## SWITCHING TEST CIRCUIT



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